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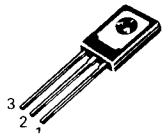
*Consult Motorola if a direct replacement is necessary.

TABLE 7 — PLASTIC TO-225 Type (Formerly TO-126 Type)

STYLE 1:
PIN 1. EMITTER
2. COLLECTOR
3. BASE



STYLE 3:
PIN 1. BASE
2. COLLECTOR
3. EMITTER

CASE 77-06

I_C Cont Amps Max	$V_{CEO(sus)}$ Volts Min	Device Type NPN	Device Type PNP	h_{FE} Min/Max	@ I_C Amp	Resistive Switching t_s μs Max	Resistive Switching t_f μs Max	Resistive Switching @ I_C Amp	f_T MHz Min	P_D (Case) Watts @ 25°C
0.3	250	MJE3440		40/160	0.02				15	15
	350	MJE3439		40/160	0.02				15	15
0.5	150	MJE341		25/200	0.05				15	20.8
	200	MJE344		30/300	0.05				15	20.8
	250	2N5655 BD157		30/250 30/240	0.1 0.05	3.5 typ	0.24 typ	0.1	10	20 20
	300	BD158 BD232 MJE340 2N5656	 MJE350 	30/240 20 min 30/240 30/250	0.05 0.15 0.05 0.1	 3.5 typ	 0.24 typ	 0.1	 10	20 20 20.8 20
	350	2N5657 BD159		30/250 30/240	0.1 0.05	3.5 typ	0.24 typ	0.1	10	20 20
1	40	2N4921	2N4918	20/100	0.5	0.6 typ	0.3 typ	0.5	3	30
	60	2N4922	2N4919	20/100	0.5	0.6 typ	0.3 typ	0.5	3	30
	80	2N4923	2N4920	20/100	0.5	0.6 typ	0.3 typ	0.5	3	30
1.5	45	BD165 BD135 BD135.6 BD135.10 BD135.16	BD166 BD136 BD136.6 BD136.10 BD136.16	15 min 40/250 40/100 63/160 100/250	0.5 0.15 0.15 0.15 0.15				6	20 12.5 12.5 12.5 12.5
	60	BD167 BD137 BD137.6 BD137.10 BD137.16	 BD138 BD138.6 BD138.10 BD138.16	15 min 40/250 40/100 63/160 100/250	0.5 0.15 0.15 0.15 0.15				6	20 12.5 12.5 12.5 12.5
	80	BD169 BD139 BD139.6 BD139.10 BD139.16	 BD140 BD140.6 BD140.10 BD140.16	15 min 40/250 40/100 63/160 100/250	0.5 0.15 0.15 0.15 0.15				6	20 12.5 12.5 12.5 12.5
	300	MJE13002•		5/25	1	4	0.7	1	5	40
	400	MJE13003•		5/25	1	4	0.7	1	5	40
2	45		BD234	25 min	1				3	25
	60	BD235	BD236	25 min	1				3	25
	80	BD237		25 min	1				3	25
	100	*MJE270##*	*MJE271##*	1.5k min	0.12				6	15
3	30	MJE520	MJE370	25 min	1					25
	40	MJE180	MJE170	50/250	0.1	0.6 typ	0.12 typ	0.1	50	12.5

• Case 77 (Style 3), # $|h_{fe}|$ @ 1 MHz, ## Darlington

(continued)

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MJE3439
MJE3440

NPN SILICON HIGH-VOLTAGE POWER TRANSISTORS

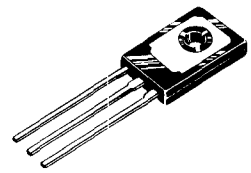
. . . designed for use in line-operated equipment requiring high f_T.

- High DC Current Gain –
  h_{FE} = 40-160 @ I_C = 20 mAdc
- Current-Gain–Bandwidth Product –
  f_T = 15 MHz (Min) @ I_C = 10 mAdc
- Low Output Capacitance –
  C_{ob} = 10 pF (Max) @ f = 1.0 MHz

0.3 AMPERE

POWER TRANSISTORS
NPN SILICON

250-350 VOLTS
15 WATTS



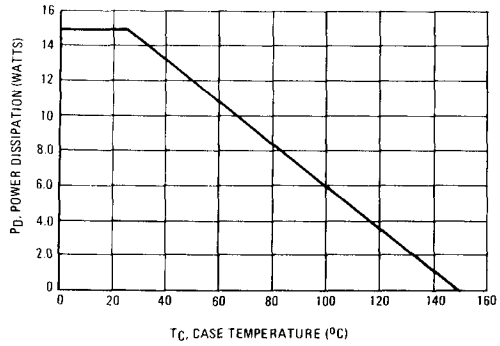
MAXIMUM RATINGS

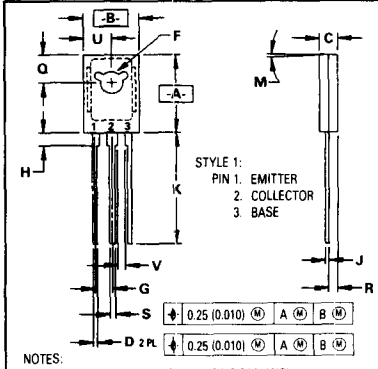
Rating	Symbol	MJE3439	MJE3440	Unit
Collector-Emitter Voltage	V_{CEO}	350	250	Vdc
Collector-Base Voltage	V_{CB}	450	350	Vdc
Emitter-Base Voltage	V_{EB}	5.0		Vdc
Collector Current – Continuous	I_C	0.3		Adc
Base Current	I_B	150		mAdc
Total Power Dissipation @ T_C = 25°C Derate above 25°C	P_D	15 0.12		Watts W/°C
Operating and Storage Junction Temperature Range	T_J,T_{stg}	-65 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	8.33	°C/W

FIGURE 1 – POWER-TEMPERATURE DERATING CURVE





NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS MIN	MILLIMETERS MAX	INCHES MIN	INCHES MAX
A	10.80	11.04	0.425	0.435
B	7.50	7.74	0.295	0.305
C	2.42	2.66	0.095	0.105
D	0.51	0.66	0.020	0.026
F	2.93	3.17	0.115	0.125
G	2.39 BSC		0.094 BSC	
H	1.27	2.41	0.050	0.095
J	0.39	0.63	0.015	0.025
K	14.61	16.63	0.575	0.655
M	3° TYP		3° TYP	
Q	3.76	4.01	0.148	0.158
R	1.15	1.39	0.045	0.055
S	0.64	0.88	0.025	0.035
U	3.69	3.93	0.145	0.155
V	1.02	—	0.040	—

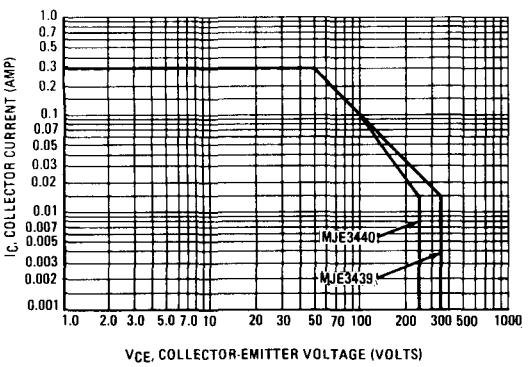
CASE 77-06
TO-225AA TYPE

3

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage		$V_{CEO(sus)}$			Vdc
(I_C = 5.0 mAdc, I_B = 0)	MJE3439		350	–	
(I_C = 50 mAdc, I_B = 0)	MJE3440		250	–	
Collector Cutoff Current		I_{CEO}			μAdc
(V_{CE} = 300 Vdc, I_B = 0)	MJE3439		–	20	
(V_{CE} = 200 Vdc, I_B = 0)	MJE3440		–	50	
Collector Cutoff Current		I_{CEX}			μAdc
(V_{CE} = 450 Vdc, $V_{EB(off)}$ = 1.5 Vdc)	MJE3439		–	500	
(V_{CE} = 300 Vdc, $V_{EB(off)}$ = 1.5 Vdc)	MJE3440		–	500	
Collector Cutoff Current		I_{CBO}			μAdc
(V_{CB} = 350 Vdc, I_E = 0)	MJE3439		–	20	
(V_{CB} = 250 Vdc, I_E = 0)	MJE3440		–	20	
Emitter Cutoff Current (V_{BE} = 5.0 Vdc, I_C = 0)		I_{EBO}	–	20	μAdc
ON CHARACTERISTICS					
DC Current Gain		h_{FE}			–
(I_C = 2.0 mAdc, V_{CE} = 10 Vdc)			30	–	
(I_C = 20 mAdc, V_{CE} = 10 Vdc)			50	200	
Collector-Emitter Saturation Voltage (I_C = 50 mAdc, I_B = 4.0 mAdc)		$V_{CE(sat)}$	–	0.5	Vdc
Base-Emitter Saturation Voltage (I_C = 50 mAdc, I_B = 4.0 mAdc)		$V_{BE(sat)}$	–	1.3	Vdc
Base-Emitter On Voltage (I_C = 50 mAdc, V_{CE} = 10 Vdc)		$V_{BE(on)}$	–	0.8	Vdc
DYNAMIC CHARACTERISTICS					
Current-Gain—Bandwidth Product (I_C = 10 mAdc, V_{CE} = 10 Vdc, f = 5.0 MHz)		f_T	15	–	MHz
Output Capacitance (V_{CB} = 10 Vdc, I_E = 0, f = 1.0 MHz)		C_{ob}	–	10	pF
Small-Signal Current Gain (I_C = 5.0 mAdc, V_{CE} = 10 Vdc, f = 1.0 kHz)		h_{fe}	25	–	–

FIGURE 2 – ACTIVE-REGION SAFE OPERATING AREA



The Safe Operating Area Curves indicate I_C–V_{CE} limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J, power-temperature derating must be observed for both steady state and pulse power conditions.

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